

PCT

INTERNATIONAL PRELIMINARY EXAMINATION REPORT

Anslation interna		EXAMINAT	
·	(PCT Article 36 and	Rule 70)	
Applicant's or agent's file reference Wa 10225-W	FOR FURTHER ACTION		on of Transmittal of Internat amination Report (Form PCT/IPEA/4
International application No. PCT/EP2003/008177	International filing date (day/m 24 July 2003 (24.07.		riority date (day/month/year) 01 August 2002 (01.08.2002)
International Patent Classification (IPC) F16C 33/24, 33/04, C04B 35			
Applicant	ESK CERAMICS GMBH	& CO. KG	
This report is also accom amended and are the basi 70.16 and Section 607 of	nt according to Article 36. I of	f the description,	claims and/or drawings which have
3. This report contains indications I Basis of the report			
II Priority			
III Non-establishm	ent of opinion with regard to novelty	y, inventive step	and industrial applicability
IV Lack of unity of	f invention		
V Reasoned stater citations and ex	nent under Article 35(2) with regard planations supporting such statement	to novelty, inver	ntive step or industrial applicability;
	ents cited		
VI Certain docume	in the international application		
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VII Certain defects	tions on the international application	1	
VII Certain defects	ations on the international application	f completion of t	his report

Form PCT/IPEA/409 (cover sheet) (July 1998)

INTERNATIONAL PRELIMINARY EXAMINATION REPORT

International application No.

PCT/EP2003/008177

I. Basis	of the re	report	
1. With	regard to	to the elements of the international application:*	
	the inte	ternational application as originally filed	
	the des	scription:	
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шсі	шешано	to the language, all the elements marked above were available or furnished to this Authority in the language is onal application was filed, unless otherwise indicated under this item. Into were available or furnished to this Authority in the following language When the second control is a second control in the second control in the second control is a second control in the second control in	
▎ٰ		nguage of a translation furnished for the purposes of international search (under Rule 23.1(b)).	
		nguage of publication of the international application (under Rule 48.3(b)).	
	the lar or 55.3	inguage of the translation furnished for the purposes of international preliminary examination (under Rule 55.3).	i.2 and/
3. With	h regard iminary e	d to any nucleotide and/or amino acid sequence disclosed in the international application, the internation was carried out on the basis of the sequence listing:	national
▎ٰ		ined in the international application in written form.	
		together with the international application in computer readable form.	
	furnish	shed subsequently to this Authority in written form.	
▎ٰٰ	furnish	shed subsequently to this Authority in computer readable form.	
	The sinterna	statement that the subsequently furnished written sequence listing does not go beyond the disclosure national application as filed has been furnished.	in the
⊔	The st	statement that the information recorded in computer readable form is identical to the written sequence list furnished.	ing has
4. 🛛	The ar	mendments have resulted in the cancellation of:	
		the description, pages	
	\boxtimes	the claims, Nos. 7-12	
		the drawings, sheets/fig	
5. 🗌	This re beyond	eport has been established as if (some of) the amendments had not been made, since they have been considered the disclosure as filed, as indicated in the Supplemental Box (Rule 70.2(c)).**	d to go
and	10.17).	t sheets which have been furnished to the receiving Office in response to an invitation under Article 14 are refe ort as "originally filed" and are not annexed to this report since they do not contain amendments (Rule	erred to
** Any	replacem	ment sheet containing such amendments must be referred to under item 1 and annexed to this report.	

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Interior No.
PCT/EP 03/08177

 Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement 					
. Statement					
Novelty (N)	Claims	2-5	YES		
	Claims	1, 6	NO		
Inventive step (IS)	Claims	3-5	YES		
	Claims	1, 2, 6	NO		
Industrial applicability (IA)	Claims	1-6	YES		
	Claims		NO		

- 2. Citations and explanations
 - 1. Reference is made to the following documents:
 - D1: QUICK NATHANIEL R.: "Laser Synthesis of Conductive Phases in Silicon Carbide Thin Film and Bulk Substrates" PROCEEDINGS OF THE INTERNATIONAL CONFERENCE ON LASERS, Vol. D, 1994, pages 696-702, XP001155543
 - D2: QUICK NATHANIEL R.: "Laser synthesis of conductive phases in silicon carbide and aluminum nitride"

 NOVEL TECHNIQUES IN SYNTHESIS AND PROCESSING OF ADVANCED MATERIALS, PROCEEDINGS OF A SYMPOSIUM,
 1995, pages 419-432, XP009018887
 - D6: WO 01/16054 A (UNIV ILLINOIS) 8 March 2001 (2001-03-08)
 - D7: WO 02/02956 A (BLEISTAHL PROD GMBH & CO KG; DALAL KIRIT (DE); SPANG WALTER (DE)) 10 January 2002 (2002-01-10)
 - 2. The subject matter of claims 1 and 6 does not appear novel (PCT Article 33(2)). The reasons are as follows:

According to claim 1, the method can be carried out in the presence of a <u>reaction gas</u>, a protective gas or in a vacuum.

Document D1 (entire document, particularly "experimental procedures" and figure 2) or document D2 (entire document, particularly "experimental procedures" and figures 2, 3 and 7) discloses a method for producing a molded body, a material with a SiC surface being heated locally in the presence of air by means of a radiation source. Air can be considered a reaction gas.

Therefore, D1 or D2 is prejudicial to the novelty of claims 1 and 6.

3. The subject matter of claim 2 does not satisfy the requirements of PCT Article 6 and PCT Article 33(3). The reasons are as follows:

Claim 2 is defined in part in terms of a result to be achieved, namely: "the reaction gas being of such a nature that it can extract the metal in the metallic carbide in the given temperature range and leave carbon behind."

Since claim 2 does not contain all of the method features essential to executing the invention, an inventive step cannot yet be acknowledged (PCT Article 33(3)).

4. The combination of claims 1 + 2 + 3 appears to satisfy the requirements of PCT Article 6 and PCT Article 33(2) and (3). The reasons are as follows:

Although documents D1 and D2 disclose a method with local heating by means of a laser, this is carried out in the presence of air and at a higher temperature.

Document D6 (page 45, lines 9-23) describes a method for converting a silicon carbide surface into carbon, a

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carrier gas (argon) that is loaded with a halogen (chlorine) being used as the reaction gas. It is further mentioned that the surface can also be structured using conventional etching processes, inter alia for self-lubricating surfaces.

However, there is nothing to suggest combining D1 or D2 with D6.

5. The subject matter of claim 5 likewise appears to satisfy the requirements of PCT Article 33(2) and (3). The reasons are as follows:

Although documents D1 and D2 disclose a method with local heating by means of a laser, this is carried out in the presence of air and at a higher temperature.

Document D7 (claims) describes a method for converting a silicon carbide surface into carbon, the SiC molded body being heated to a temperature of between 1600 and 2200°C in a vacuum or a protective gas.

However, there is nothing to suggest combining D1 or D2 with D7.

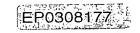
The method according to claims 3 and 5 prevents the carbon that is formed from being oxidized.

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Patentansprüche

- 1. Verfahren zur Herstellung eines Formkörpers, dadurch gekennzeichnet, dass ein Werkstoff mit einer Metallcarbid-Oberfläche in Anwesenheit eines Reaktionsgases, eines Schutzgases oder in einem Vakuum mittels einer Strahlungsquelle in einem definierten Bereich seiner Oberfläche derart erhitzt wird, dass es in diesem Bereich zu einer lokalen Umwandlung des Metallcarbids in Kohlenstoff kommt.
- 2. Verfahren nach Anspruch 1, dadurch gekennzeichnet, dass das Metallcarbid mit Hilfe einer Strahlungsquelle lokal bestrahlt und dabei auf 600-1500°C erhitzt wird und die Metallcarbid-Oberfläche dabei einem Reaktionsgas ausgesetzt wird, wobei das Reaktionsgas derart beschaffen ist, dass es in dem vorgegebenen Temperaturbereich das Metall des Metallcarbids herauszulösen vermag und Kohlenstoff zurücklässt.
 - 3. Verfahren nach Anspruch 2, dadurch gekennzeichnet, dass als Reaktionsgas ein mit einem Halogen versetztes Trägergas verwendet wird.
- 4. Verfahren nach Anspruch 3, dadurch gekennzeichnet, dass als Halogen Chlor und als Trägergas Argon verwendet wird.
 - 5. Verfahren nach Anspruch 1, dadurch gekennzeichnet, dass die mit einer Strahlungsquelle bestrahlte Oberfläche lokal auf mehr als 1500°C und weniger als 2200°C erhitzt wird und einem Vakuum oder Schutzgas ausgesetzt wird, wobei sich Metallcarbid ohne Beteiligung fremder Elemente in Metall und Kohlenstoff zersetzt.
- 6. Verfahren nach einem der Ansprüche 1 bis 5, dadurch gekennzeichnet, dass als Strahlungsquelle ein Laser, eine Mikrowelle oder ein Elektronenstrahl verwendet wird.